

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	166	polycrystalline near silicon near island\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/15 14:54
L2	1205	pattern\$3 near polycrystalline near silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/15 14:55
L3	13	1 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/15 14:55
S1	6	("6256231" or ("6181597" or ("6081456")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2004/12/14 09:10
S2	5	("5768192" "5793666" "5844839" "5875128" "5936887").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 09:11
S3	4	("4380057" "5768192" "6011725" "6044022").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 09:13
S4	2	("5168334" "5768192").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 09:14
S5	7	("4360900" "4373248" "4377818" "4451904" "4597060" "4768080" "4774556").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 09:15
S6	2	("5568425" "5768192").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:18
S7	3179	257/2-5,16,52-63,646.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:18
S8	1	S7 and SONOS	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/15 15:00
S9	4	("20030222318" "4810673" "6410210" "6704188").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:31
S10	9	("4610771" "5472829" "5529524" "5591566" "5619097" "5733712" "5846693" "5935765" "6162588").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:38

S11	570673	"257"/\$.ccls. "438"/\$.ccls. "365"/\$.ccls. "430"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 11:39
S12	780	S11 and SONOS	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 12:00
S13	831	S11 and SONOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 11:40
S14	23	S13 and (uv near \$2radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 11:43
S15	8	("20010046731" "20030096475" "5863462" "5935705" "6090358" "6198216" "6444568" "6475895").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:56
S16	4	SONOS with (uv near \$2radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 12:01
S17	37	SONOS and (uv near \$2radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:48
S18	3105	SONOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:45
S19	1	S18 and ((polycrystalline near silicon) with (silicon near rich))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:56
S20	48264	(uv near \$2radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:48

S22	8	S20 and ((polycrystalline near silicon) and (silicon near rich))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:49
S23	73	S18 and (barrier near (film layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 17:42
S24	6	S18 and ((barrier near (film layer)) with (silicon near nitride))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 17:42
S33	8	((barrier near (film layer)) (silicon near nitride)) and SONOS and (metal near dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 17:45